



FEATURES

Ultra low power consumption:

0.35mA/Channel

High data rate: π 12xAxx: 600Mbps

π 12xExx: 200Mbps

π 12xMxx: 10Mbps

π 12xUxx: 150kbps

High common-mode transient immunity: 150 kV/ μ s typical

High robustness to radiated and conducted noise

Isolation voltages:

π 12xx3x: AC 3000Vrms

π 12xx6x: AC 6000Vrms

High ESD rating:

ESDA/JEDEC JS-001-2017

Human body model (HBM) \pm 7kV, all pins

Safety and regulatory approvals:

UL certificate number: E494497

3000Vrms/6000Vrms for 1 minute per UL 1577

CSA Component Acceptance Notice 5A(Pending)

VDE certificate number: 40047929

DIN V VDE V 0884-10 (VDE V 0884-10):2006-12

V_{IORM} = 565V peak/849V peak

CQC certification per GB4943.1-2011(Pending)

3 V to 5.5 V level translation

Wide temperature range: -40°C to 125°C

8/16-lead, RoHS-compliant, (W)SOIC package

APPLICATIONS

General-purpose multichannel isolation

Industrial field bus isolation

GENERAL DESCRIPTION

The π 1xxxx are 2PaiSemi digital isolators product family. By using matured standard semiconductor CMOS technology and innovative design, these isolation components provide outstanding performance characteristics superior to alternatives such as optocoupler devices and other integrated isolators. The π 1xxxx isolator data channels are independent and are available in a variety of configurations with a withstand voltage rating of 3.0 kV rms to 6.0 kV rms and the data rate from DC up to 600Mbps (see the Ordering Guide). The devices operate with the supply voltage on either side ranging from 3.0 V to 5.5 V, providing compatibility with lower voltage systems as well as enabling voltage translation functionality across the isolation barrier.

The fail-safe state is available in which the outputs transition to a preset state when the input power supply is not applied.

FUNCTIONAL BLOCK DIAGRAMS

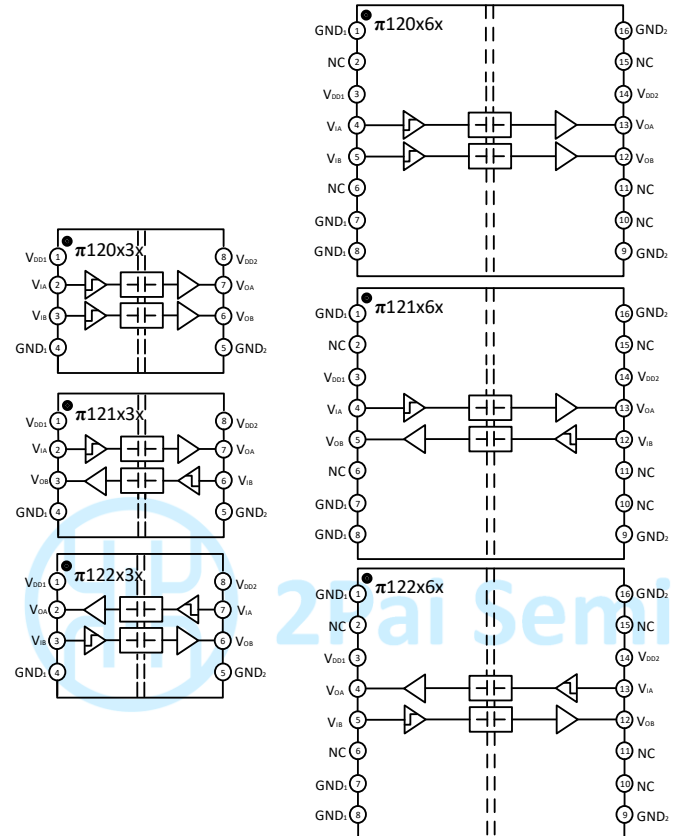


Figure1. π 120xxx/ π 121xxx/ π 122xxx functional Block Diagram

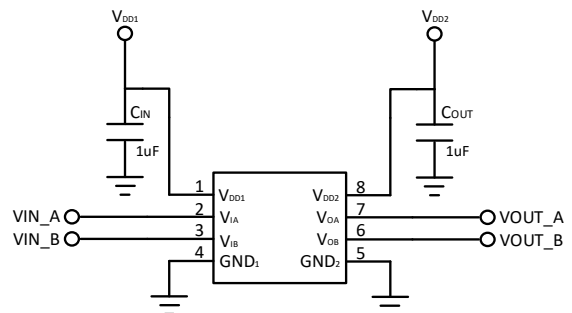


Figure2. π 120xxx Typical Application Circuit

PIN CONFIGURATIONS AND FUNCTIONS

π 120U3x Pin Function Descriptions

Pin No.	Name	Description
1	V _{DD1}	Supply Voltage for Isolator Side 1.
2	V _{IA}	Logic Input A.
3	V _{IB}	Logic Input B.
4	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
5	GND ₂	Ground 2. This pin is the ground reference for Isolator Side 2.
6	V _{OB}	Logic Output B.
7	V _{OA}	Logic Output A.
8	V _{DD2}	Supply Voltage for Isolator Side 2.

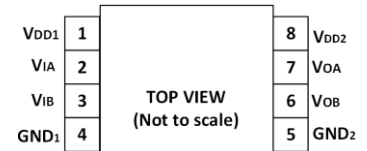


Figure3. π 120U3x Pin Configuration

π 121U3x Pin Function Descriptions

Pin No.	Name	Description
1	V _{DD1}	Supply Voltage for Isolator Side 1.
2	V _{IA}	Logic Input A.
3	V _{OB}	Logic Output B.
4	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
5	GND ₂	Ground 2. This pin is the ground reference for Isolator Side 2.
6	V _{IB}	Logic Input B.
7	V _{OA}	Logic Output A.
8	V _{DD2}	Supply Voltage for Isolator Side 2.

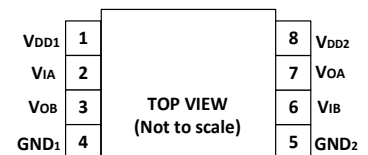


Figure4. π 121U3x Pin Configuration

π 122U3x Pin Function Descriptions

Pin No.	Name	Description
1	V _{DD1}	Supply Voltage for Isolator Side 1.
2	V _{OA}	Logic Output A.
3	V _{IB}	Logic Input B.
4	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
5	GND ₂	Ground 2. This pin is the ground reference for Isolator Side 2.
6	V _{OB}	Logic Output B.
7	V _{IA}	Logic Input A.
8	V _{DD2}	Supply Voltage for Isolator Side 2.

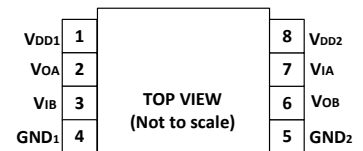


Figure5. π 122U3x Pin Configuration

π 120U6x Pin Function Descriptions

Pin No.	Name	Description
1	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
2	NC	No connect.
3	V _{DD1}	Supply Voltage for Isolator Side 1.
4	V _{IA}	Logic Input A.
5	V _{IB}	Logic Input B.
6	NC	No Connect.
7	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
8	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
9	GND ₂	Ground 2. This pin is the ground reference for Isolator Side 2.

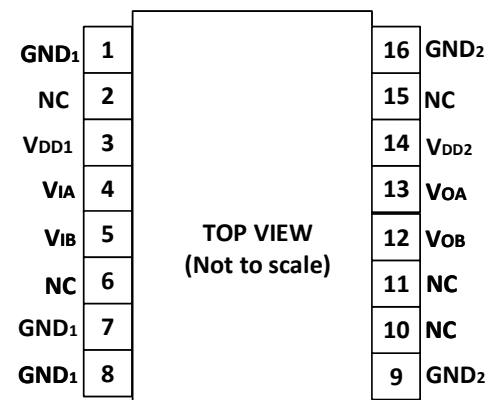


Figure6. π 120U6x Pin Configuration

10	NC	No Connect.
11	NC	No Connect.
12	V _{OB}	Logic Output B.
13	V _{OA}	Logic Output A.
14	V _{DD2}	Supply Voltage for Isolator Side 2.
15	NC	No Connect.
16	GND ₂	Ground 2. This pin is the ground reference for Isolator Side 2.

π 121U6x Pin Function Descriptions

Pin No.	Name	Description
1	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
2	NC	No Connect.
3	V _{DD1}	Supply Voltage for Isolator Side 1.
4	V _{IA}	Logic Input A.
5	V _{OB}	Logic Output B.
6	NC	No Connect.
7	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
8	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
9	GND ₂	Ground 2. This pin is the ground reference for Isolator Side 2.
10	NC	No Connect.
11	NC	No Connect.
12	V _{IB}	Logic Input B.
13	V _{OA}	Logic Output A.
14	V _{DD2}	Supply Voltage for Isolator Side 2.
15	NC	No Connect.
16	GND ₂	Ground 2. This pin is the ground reference for Isolator Side 2.

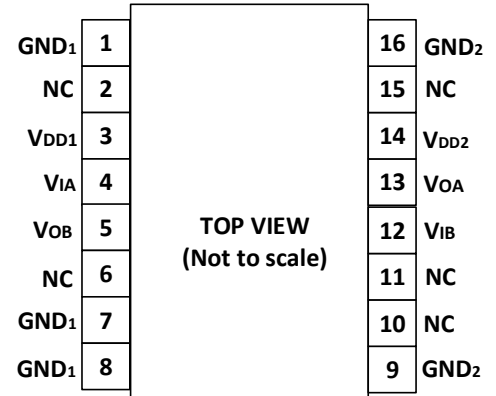


Figure7. π 121U6x Pin Configuration

π 122U6x Pin Function Descriptions

Pin No.	Name	Description
1	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
2	NC	No Connect.
3	V _{DD1}	Supply Voltage for Isolator Side 1.
4	V _{OA}	Logic Output A.
5	V _{IB}	Logic Input B.
6	NC	No Connect.
7	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
8	GND ₁	Ground 1. This pin is the ground reference for Isolator Side 1.
9	GND ₂	Ground 2. This pin is the ground reference for Isolator Side 2.
10	NC	No Connect.
11	NC	No Connect.
12	V _{OB}	Logic Output B.
13	V _{IA}	Logic Input A.
14	V _{DD2}	Supply Voltage for Isolator Side 2.
15	NC	No Connect.
16	GND ₂	Ground 2. This pin is the ground reference for Isolator Side 2.

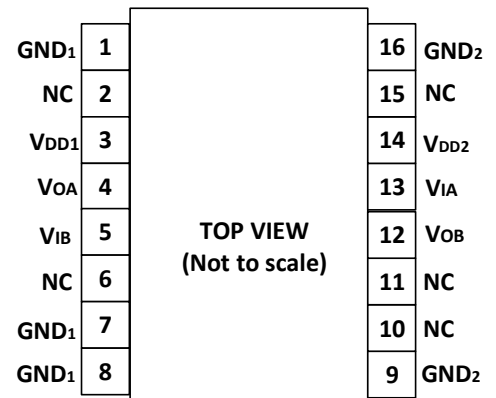


Figure8. π 122U6x Pin Configuration

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 1. Absolute Maximum Ratings⁴

Parameter	Rating
Supply Voltages ($V_{DD1-GND1}$, $V_{DD2-GND2}$)	-0.5 V to +7.0 V
Input Voltages (V_{IA} , V_{IB}) ¹	-0.5 V to $V_{DDx} + 0.5$ V
Output Voltages (V_{OA} , V_{OB}) ¹	-0.5 V to $V_{DDx} + 0.5$ V
Average Output Current per Pin ² Side 1 Output Current (I_{O1})	-10 mA to +10 mA
Average Output Current per Pin ² Side 2 Output Current (I_{O2})	-10 mA to +10 mA
Common-Mode Transients Immunity ³	-200 kV/ μs to +200 kV/ μs
Storage Temperature (T_{ST}) Range	-65°C to +150°C
Ambient Operating Temperature (T_A) Range	-40°C to +125°C

Notes:

¹ V_{DDx} is the side voltage power supply V_{DD} , where x = 1 or 2.

² See Figure9 for the maximum rated current values for various temperatures.

³ See Figure19 for Common-mode transient immunity (CMTI) measurement.

⁴ Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

RECOMMENDED OPERATING CONDITIONS

Table 2. Recommended Operating Conditions

Parameter	Symbol	Min	Typ	Max	Unit
Supply Voltage	V_{DDx} ¹	3		5.5	V
High Level Input Signal Voltage	V_{IH}	$0.7 * V_{DDx}$ ¹		V_{DDx} ¹	V
Low Level Input Signal Voltage	V_{IL}	0		$0.3 * V_{DDx}$ ¹	V
High Level Output Current	I_{OH}	-6			mA
Low Level Output Current	I_{OL}			6	mA
Maximum Data Rate		0		150	Kbps
Junction Temperature	T_J	-40		150	°C
Ambient Operating Temperature	T_A	-40		125	°C

Notes:

¹ V_{DDx} is the side voltage power supply V_{DD} , where x = 1 or 2.

Truth Tables

Table 3. $\pi 120xxx/\pi 121xxx/\pi 122xxx$ Truth Table

V_{IX} Input ¹	V_{DDI} State ¹	V_{DDO} State ¹	Default Low V_{OX} Output ¹	Default High V_{OX} Output ¹	Test Conditions /Comments
Low	Powered ²	Powered ²	Low	Low	Normal operation
High	Powered ²	Powered ²	High	High	Normal operation
Open	Powered ²	Powered ²	Low	High	Default output
Don't Care ⁴	Unpowered ³	Powered ²	Low	High	Default output ⁵
Don't Care ⁴	Powered ²	Unpowered ³	High Impedance	High Impedance	

Notes:

¹ V_{IX}/V_{OX} are the input/output signals of a given channel (A or B). V_{DDI}/V_{DDO} are the supply voltages on the input/output signal sides of this given channel.

² Powered means $V_{DDx} \geq 2.9V$

³ Unpowered means $V_{DDx} < 2.3V$

⁴ Input signal (V_{ix}) must be in a low state to avoid powering the given V_{DD1} through its ESD protection circuitry.

⁵ If the V_{DD1} goes into unpowered status, the channel outputs the default logic signal after around 1us. If the V_{DD1} goes into powered status, the channel outputs the input status logic signal after around 1us.

SPECIFICATIONS

ELECTRICAL CHARACTERISTICS

Table 4. Switching Specifications

$V_{DD1} - V_{GND1} = V_{DD2} - V_{GND2} = 3.3V_{DC} \pm 10\%$ or $5V_{DC} \pm 10\%$, $T_A = 25^\circ C$, unless otherwise noted.

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions/Comments
Minimum Pulse Width	PW			6.5	us	Within pulse width distortion (PWD) limit
Maximum Data Rate		150			Kbps	Within PWD limit
Propagation Delay Time ^{1,4}	t_{pHL}, t_{pLH}		3.0		us	The different time between 50% input signal to 50% output signal 50% @ $5V_{DC}$ supply
			3.05		us	@ $3.3V_{DC}$ supply
Pulse Width Distortion ⁴	PWD	0	0.02	0.1	us	The max different time between t_{pHL} and t_{pLH} @ $5V_{DC}$ supply. And The value is $ t_{pHL} - t_{pLH} $
		0	0.02	0.1	us	@ $3.3V_{DC}$ supply
Part to Part Propagation Delay Skew ⁴	t_{PSK}			0.2	us	The max different propagation delay time between any two devices at the same temperature, load and voltage @ $5V_{DC}$ supply
				0.2	us	@ $3.3V_{DC}$ supply
Channel to Channel Propagation Delay Skew ⁴	t_{CSK}	0	0.1	0.1	us	The max amount propagation delay time differs between any two output channels in the single device @ $5V_{DC}$ supply.
		0	0.1	0.1	us	@ $3.3V_{DC}$ supply
Output Signal Rise/Fall Time ⁴	t_r/t_f		0.7		ns	10% to 90% signal terminated 50Ω , See figure15.
Common-Mode Transient Immunity ³	CMTI		150		kV/ μs	$V_{IN} = V_{DDx}^2$ or 0V, $V_{CM} = 1000V$.
ESD (HBM - Human body model)	ESD		± 7		kV	all pins

Notes:

¹ t_{pLH} = low-to-high propagation delay time, t_{pHL} = high-to-low propagation delay time. See figure 16.

² V_{DDx} is the side voltage power supply V_{DD} , where $x = 1$ or 2 .

³ See Figure19 for Common-mode transient immunity (CMTI) measurement.

⁴ Output Signal Terminated 50Ω .

Table 5. DC Specifications

$V_{DD1} - V_{GND1} = V_{DD2} - V_{GND2} = 3.3V_{DC} \pm 10\%$ or $5V_{DC} \pm 10\%$, $T_A = 25^\circ C$, unless otherwise noted.

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions/Comments
High Level Input Signal Voltage	V_{IH}			$0.7 * V_{DDx}^1$	V	
Low Level Input Signal Voltage	V_{IL}	$0.3 * V_{DDx}^1$			V	
High Level Output Voltage	V_{OH}^1	$V_{DDx} - 0.1$	V_{DDx}		V	$-20 \mu A$ output signal
		$V_{DDx} - 0.2$	$V_{DDx} - 0.1$		V	$-2 mA$ output signal
Low Level Output Voltage	V_{OL}		0	0.1	V	$20 \mu A$ output signal
			0.1	0.2	V	$2 mA$ output signal
Input Current per Signal Channel	I_{IN}	-10	0.5	10	μA	$0V \leq \text{Signal voltage} \leq V_{DDx}^1$

V_{DDx}^1 Undervoltage Rising Threshold	V_{DDxUV+}	2.45	2.65	2.9	V
V_{DDx}^1 Undervoltage Falling Threshold	V_{DDxUV-}	2.3	2.5	2.75	V
V_{DDx}^1 Hysteresis	V_{DDxUVH}	0.15			V

Notes:

¹ V_{DDx} is the side voltage power supply V_{DD} , where x = 1 or 2.**Table 6. Quiescent Supply Current** $V_{DD1} - V_{GND1} = V_{DD2} - V_{GND2} = 3.3V_{DC} \pm 10\%$ or $5V_{DC} \pm 10\%$, $T_A = 25^\circ C$, $C_L = 0$ pF, unless otherwise noted.

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions	
$\pi 120U_{xx}$ Quiescent Supply Current @ $5V_{DC}$ Supply	$I_{DD1}(Q)$	120	150	195	μA	0V Input signal	
	$I_{DD2}(Q)$	531	664	863	μA	0V Input signal	
	$I_{DD1}(Q)$	120	151	196	μA	5V Input signal	
	$I_{DD2}(Q)$	467	584	759	μA	5V Input signal	
	@ $3.3V_{DC}$ Supply	$I_{DD1}(Q)$	91	114	148	μA	0V Input signal
		$I_{DD2}(Q)$	523	654	850	μA	0V Input signal
		$I_{DD1}(Q)$	91	114	148	μA	3.3V Input signal
		$I_{DD2}(Q)$	472	590	766	μA	3.3V Input signal
$\pi 121U_{xx}$ Quiescent Supply Current @ $5V_{DC}$ Supply	$I_{DD1}(Q)$	325	407	529	μA	0V Input signal	
	$I_{DD2}(Q)$	325	407	529	μA	0V Input signal	
	$I_{DD1}(Q)$	294	367	477	μA	5V Input signal	
	$I_{DD2}(Q)$	294	367	477	μA	5V Input signal	
	@ $3.3V_{DC}$ Supply	$I_{DD1}(Q)$	307	384	499	μA	0V Input signal
		$I_{DD2}(Q)$	307	384	499	μA	0V Input signal
		$I_{DD1}(Q)$	281	352	457	μA	3.3V Input signal
		$I_{DD2}(Q)$	281	352	457	μA	3.3V Input signal
$\pi 122U_{xx}$ Quiescent Supply Current @ $5V_{DC}$ Supply	$I_{DD1}(Q)$	325	407	529	μA	0V Input signal	
	$I_{DD2}(Q)$	325	407	529	μA	0V Input signal	
	$I_{DD1}(Q)$	294	367	477	μA	5V Input signal	
	$I_{DD2}(Q)$	294	367	477	μA	5V Input signal	
	@ $3.3V_{DC}$ Supply	$I_{DD1}(Q)$	307	384	499	μA	0V Input signal
		$I_{DD2}(Q)$	307	384	499	μA	0V Input signal
		$I_{DD1}(Q)$	281	352	457	μA	3.3V Input signal
		$I_{DD2}(Q)$	281	352	457	μA	3.3V Input signal

Table 7. Total Supply Current vs. Data Throughput ($C_L = 0$ pF) $V_{DD1} - V_{GND1} = V_{DD2} - V_{GND2} = 3.3V_{DC} \pm 10\%$ or $5V_{DC} \pm 10\%$, $T_A = 25^\circ C$, $C_L = 0$ pF, unless otherwise noted.

Parameter	Symbol	2 Kbps			50 Kbps			150 Kbps			Unit	
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max		
$\pi 120U_{xx}$ Supply Current @ $5V_{DC}$	I_{DD1}	0.15	0.23		0.15	0.23		0.15	0.23		mA	
	I_{DD2}	0.51	0.77		0.52	0.78		0.52	0.79		mA	
	@ $3.3V_{DC}$	I_{DD1}	0.11	0.17		0.11	0.17		0.11	0.17		mA
		I_{DD2}	0.51	0.76		0.51	0.7605		0.51	0.77		mA
$\pi 121U_{xx}$ Supply Current @ $5V_{DC}$	I_{DD1}	0.33	0.50		0.33	0.50		0.34	0.51		mA	
	I_{DD2}	0.33	0.50		0.33	0.50		0.34	0.51		mA	

@ 3.3V _{DC}	I _{DD1}	0.31	0.46	0.31	0.47	0.31	0.47	mA
	I _{DD2}	0.31	0.46	0.31	0.47	0.31	0.47	mA
$\pi 122U_{xx}$ Supply Current @ 5V _{DC}	I _{DD1}	0.33	0.50	0.33	0.50	0.34	0.51	mA
	I _{DD2}	0.33	0.50	0.33	0.50	0.34	0.51	mA
@ 3.3V _{DC}	I _{DD1}	0.31	0.46	0.31	0.47	0.31	0.47	mA
	I _{DD2}	0.31	0.46	0.31	0.47	0.31	0.47	mA

INSULATION AND SAFETY RELATED SPECIFICATIONS

Table 8. Insulation Specifications

Parameter	Symbol	Value		Unit	Test Conditions/Comments
		$\pi 12xU3x$	$\pi 12xU6x$		
Rated Dielectric Insulation Voltage		3000	6000	V rms	1-minute duration
Minimum External Air Gap (Clearance)	L (CLR)	4	**	mm min	Measured from input terminals to output terminals, shortest distance through air
Minimum External Tracking (Creepage)	L (CRP)	4	**	mm min	Measured from input terminals to output terminals, shortest distance path along body
Minimum Clearance in the Plane of the Printed Circuit Board (PCB Clearance)	L (PCB)	4.5	**	mm min	Measured from input terminals to output terminals, shortest distance through air, line of sight, in the PCB mounting plane
Minimum Internal Gap (Internal Clearance)		8	**	μ m min	Insulation distance through insulation
Tracking Resistance (Comparative Tracking Index)	CTI	>400	**	V	DIN IEC 112/VDE 0303 Part 1
Material Group		II	**		Material Group (DIN VDE 0110, 1/89, Table 1)

PACKAGE CHARACTERISTICS

Table 9. Package Characteristics

Parameter	Symbol	Typical Value		Unit	Test Conditions/Comments
		$\pi 12xU3x$	$\pi 12xU6x$		
Resistance (Input to Output) ¹	R _{I-O}	10 ¹¹	10 ¹¹	Ω	
Capacitance (Input to Output) ¹	C _{I-O}	0.6	0.6	pF	@1MHz
Input Capacitance ²	C _I	3	3	pF	@1MHz
IC Junction to Ambient Thermal Resistance	θ_{JA}	100	45	$^{\circ}$ C/W	Thermocouple located at center of package underside

Notes:

¹The device is considered a 2-terminal device; SOIC-8 Pin 1 - Pin 4(WSOIC-16 Pin 1-Pin8) are shorted together as the one terminal, and SOIC-8 Pin 5 - Pin 8(WSOIC-16 Pin 9-Pin16) are shorted together as the other terminal.

²Testing from the input signal pin to ground.

REGULATORY INFORMATION

See Table 10 and the Insulation Lifetime section for details regarding recommended maximum working voltages for specific cross isolation waveforms and insulation levels.

Table10. Regulatory

Regulatory	$\pi 12xU3x$	$\pi 12xU6x$
UL	Recognized under UL 1577 Component Recognition Program ¹ Single Protection, 3000 V rms Isolation Voltage	Recognized under UL 1577 Component Recognition Program ¹ Single Protection, *** V rms Isolation Voltage

	File (E494497)	File (pending)
CSA	Approved under CSA Component Acceptance Notice 5A CSA 60950-1-07+A1+A2 and IEC 60950-1, second edition, +A1+A2: Basic insulation at 400 V rms (565 V peak) Reinforced insulation at 200 V rms (283 V peak) File (pending)	Approved under CSA Component Acceptance Notice 5A CSA 60950-1-07+A1+A2 and IEC 60950-1, second edition, +A1+A2: Basic insulation at *** V rms (**** V peak) Reinforced insulation at *** V rms (*** V peak) File (pending)
VDE	DIN V VDE V 0884-10 (VDE V 0884-10):2006-12 ² Basic insulation, $V_{IORM} = 565$ V peak, $V_{IOSM} = 4615$ V peak File (40047929)	DIN V VDE V 0884-10 (VDE V 0884-10):2006-12 ² Basic insulation, $V_{IORM} = ***$ V peak, $V_{IOSM} = ****$ V peak Reinforced insulation, $V_{IORM} = ****$ V peak, $V_{IOSM} = 10$ kV peak File (pending)
CQC	Certified under CQC11-471543-2012 GB4943.1-2011 Basic insulation at 400 V rms (565 V peak) working voltage Reinforced insulation at 200 V rms (283 V peak) File (pending)	Certified under CQC11-471543-2012 GB4943.1-2011 Basic insulation at *** V rms (*** V peak) working voltage Reinforced insulation at *** V rms (*** V peak) File (pending)

Notes:

¹ In accordance with UL 1577, each $\pi 120U3x/\pi 121U3x/\pi 122U3x$ is proof tested by applying an insulation test voltage ≥ 3600 V rms for 1 sec; each $\pi 120U6x/\pi 121U6x/\pi 122U6x$ is proof tested by applying an insulation test voltage ≥ 7200 V rms for 1 sec

² In accordance with DIN V VDE V 0884-10, each $\pi 120U3x/\pi 121U3x/\pi 122U3x$ is proof tested by applying an insulation test voltage ≥ 1059 V peak for 1 sec (partial discharge detection limit = 5 pC); each $\pi 120U6x/\pi 121U6x/\pi 122U6x$ is proof tested by $\geq ***$ V peak for 1 sec. The * marking branded on the component designates DIN V VDE V 0884-10 approval.

DIN V VDE V 0884-10 (VDE V 0884-10) INSULATION CHARACTERISTICS

These isolators are suitable for reinforced electrical isolation only within the safety limit data. Protective circuits ensure the maintenance of the safety data. The * marking on packages denotes DIN V VDE V 0884-10 approval.

Table 11. VDE Insulation Characteristics

Description	Test Conditions/Comments	Symbol	Characteristic		Unit
			$\pi 12xx3x$	$\pi 12xx6x$	
Installation Classification per DIN VDE 0110					
For Rated Mains Voltage ≤ 150 V rms			I to IV	***	
For Rated Mains Voltage ≤ 300 V rms			I to III	***	
For Rated Mains Voltage ≤ 400 V rms			I to III	***	
Climatic Classification			40/105/21	***	
Pollution Degree per DIN VDE 0110, Table 1			2	*	
Maximum Working Insulation Voltage		V_{IORM}	565	***	V peak
Input to Output Test Voltage, Method B1	$V_{IORM} \times 1.875 = V_{pd(m)}$, 100% production test, $t_{ini} = t_m = 1$ sec, partial discharge < 5 pC	$V_{pd(m)}$	1059	***	V peak
Input to Output Test Voltage, Method A					
After Environmental Tests Subgroup 1	$V_{IORM} \times 1.5 = V_{pd(m)}$, $t_{ini} = 60$ sec, $t_m = 10$ sec, partial discharge < 5 pC	$V_{pd(m)}$	848	***	V peak

After Input and/or Safety Test Subgroup 2 and Subgroup 3	$V_{IORM} \times 1.2 = V_{pd(m)}$, $t_{ini} = 60$ sec, $t_m = 10$ sec, partial discharge < 5 pC				
Highest Allowable Overvoltage		V_{IOTM}	4200	***	V peak
Surge Isolation Voltage Basic	Basic insulation, 1.2 μ s rise time, 50 μ s, 50% fall time	V_{IOSM}	4615	***	V peak
Surge Isolation Voltage Reinforced	Reinforced insulation, 1.2 μ s rise time, 50 μ s, 50% fall time	V_{IOSM}		***	V peak
Safety Limiting Values	Maximum value allowed in the event of a failure (see Figure 3)				
Maximum Junction Temperature		T_S	150	***	$^{\circ}C$
Total Power Dissipation at 25 $^{\circ}C$		P_S	1.56	***	W
Insulation Resistance at T_S	$V_{IO} = 800$ V	R_S	>10 ⁹	***	Ω

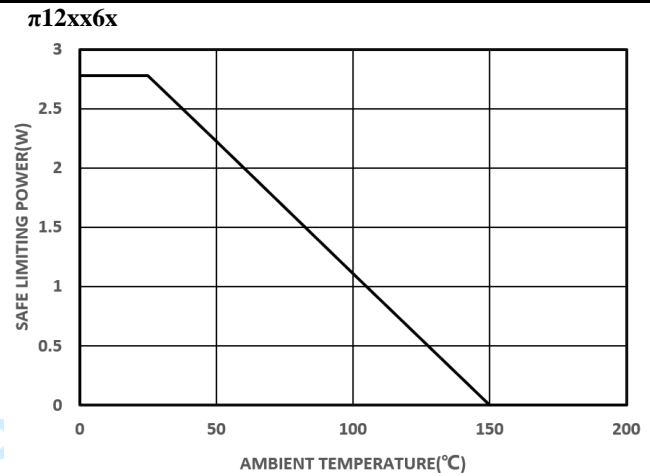
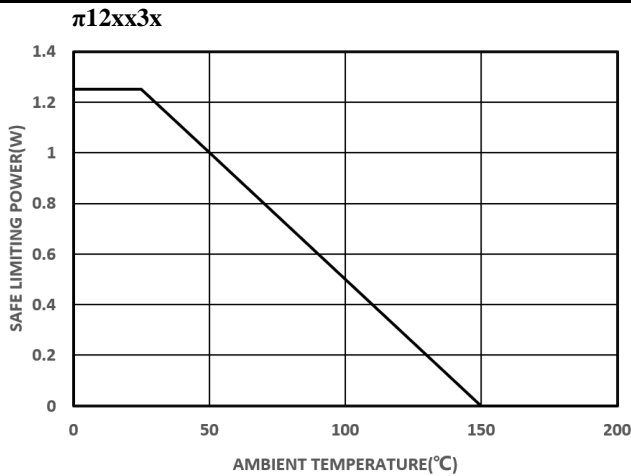


Figure9. Thermal Derating Curve, Dependence of Safety Limiting Values with Ambient Temperature per VDE

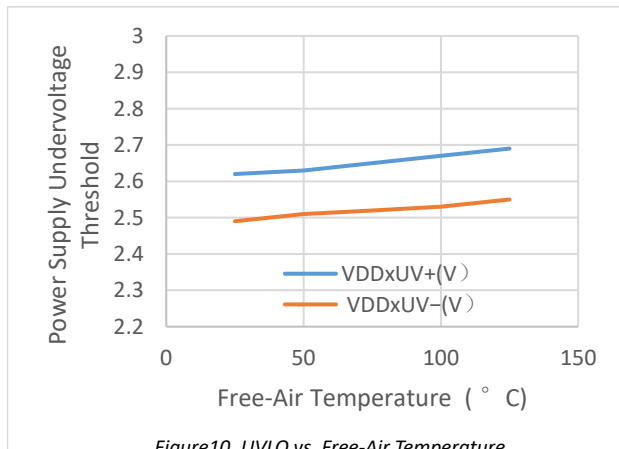


Figure10. UVLO vs. Free-Air Temperature

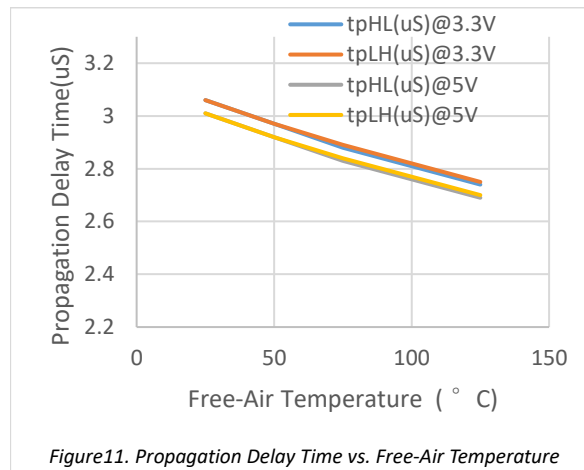


Figure11. Propagation Delay Time vs. Free-Air Temperature

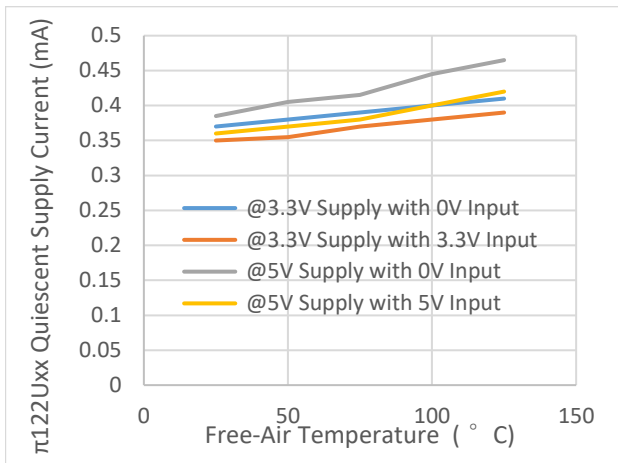


Figure12. π 121Uxx/ π 122Uxx Quiescent Supply Current vs. Free-Air Temperature

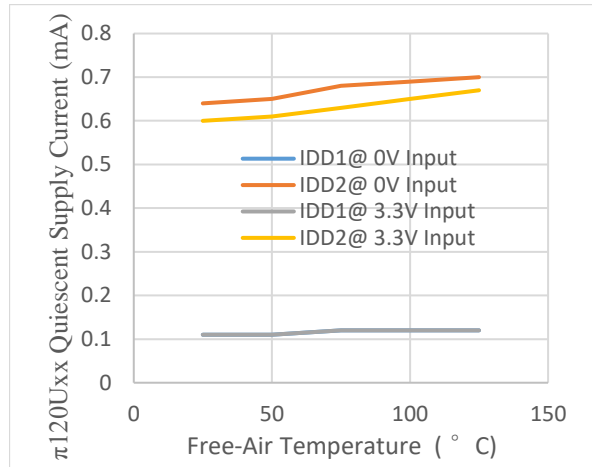


Figure13. π 120Uxx Quiescent Supply Current with 3.3V Supply vs. Free-Air Temperature

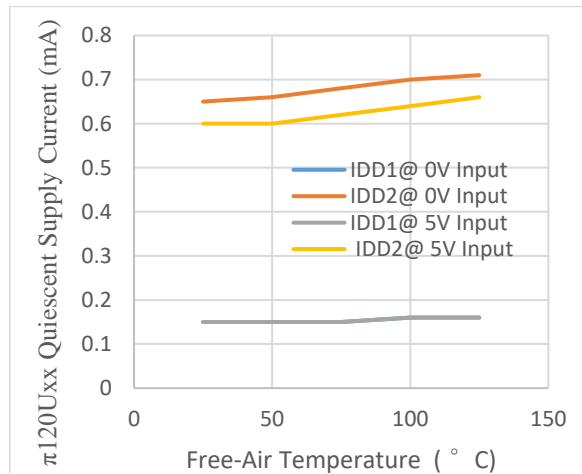


Figure14. π 120Uxx Quiescent Supply Current with 5V Supply vs. Free-Air Temperature

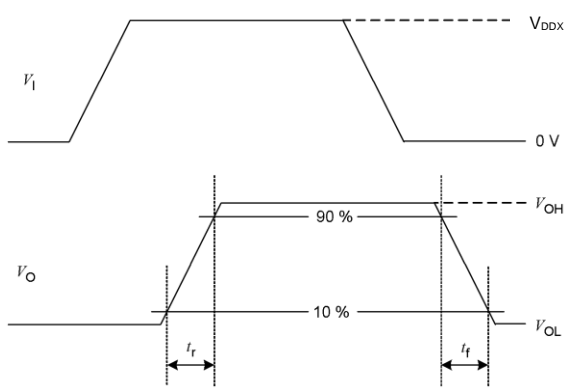


Figure15. Transition time waveform measurement

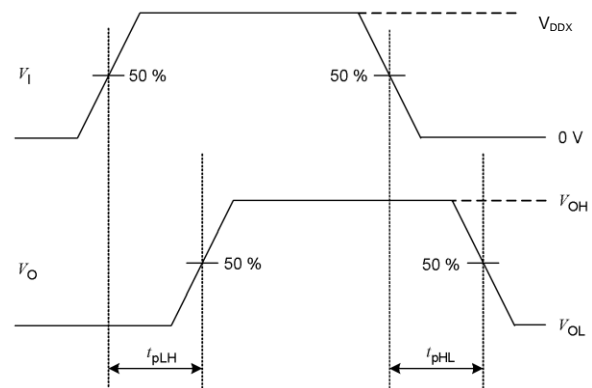


Figure16. Propagation delay time waveform measurement

APPLICATIONS INFORMATION

OVERVIEW

The $\pi 1xxxxx$ are 2PaiSemi digital isolators product family. By using matured standard semiconductor CMOS technology and innovative design, these isolation components provide outstanding performance characteristics superior to alternatives such as optocoupler devices and other integrated isolators. The $\pi 1xxxxx$ isolator data channels are independent and are available in a variety of configurations with a withstand voltage rating of 3.0 kV rms to 6.0 kV rms and the data rate from DC up to 600Mbps (see the Ordering Guide).

The $\pi 120Uxx/\pi 121Uxx/\pi 122Uxx$ are the outstanding 150 Kbps dual-channel digital isolators with the enhanced ESD capability. the devices transmit data across an isolation barrier by layers of silicon dioxide isolation.

The devices operate with the supply voltage on either side ranging from 3.0 V to 5.5 V, offering voltage translation of 3.3 V and 5 V logic.

The $\pi 120Uxx/\pi 121Uxx/\pi 122Uxx$ have low propagation delay and high speed. The input/output design techniques allow logic and supply voltages over a wide range from 3.0 V to 5.5 V, offering voltage translation of 3.3 V and 5 V logic. The architecture is designed for high common-mode transient immunity and high immunity to electrical noise and magnetic interference.

See the Ordering Guide for the model numbers that have the fail-safe output state of low or high.

PCB LAYOUT

The low-ESR ceramic bypass capacitors must be connected between V_{DD1} and GND_1 and between V_{DD2} and GND_2 . The bypass capacitors are placed on the PCB as close to the isolator device as possible. The recommended bypass capacitor value is between 0.1 μF and 10 μF .

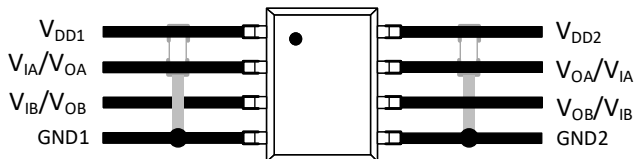


Figure17.Recommended Printed Circuit Board Layout

Avoid reducing the isolation capability, Keep the space underneath the isolator device free from metal such as planes, pads, traces and vias.

To minimize the impedance of the signal return loop, keep the solid ground plane directly underneath the high-speed signal path, the closer the better. The return path will couple between the

nearest ground plane to the signal path. Keep suitable trace width for controlled impedance transmission lines interconnect.

To reduce the rise time degradation, keep the length of input/output signal traces as short as possible, and route low inductance loop for the signal path and It's return path.

CMTI MEASUREMENT

To measure the Common-Mode Transient Immunity (CMTI) of $\pi 1xxxxx$ isolator under specified common-mode pulse magnitude (V_{CM}) and specified slew rate of the common-mode pulse (dV_{CM}/dt) and other specified test or ambient conditions, The

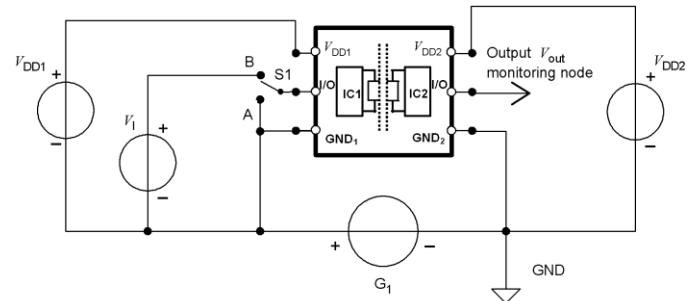
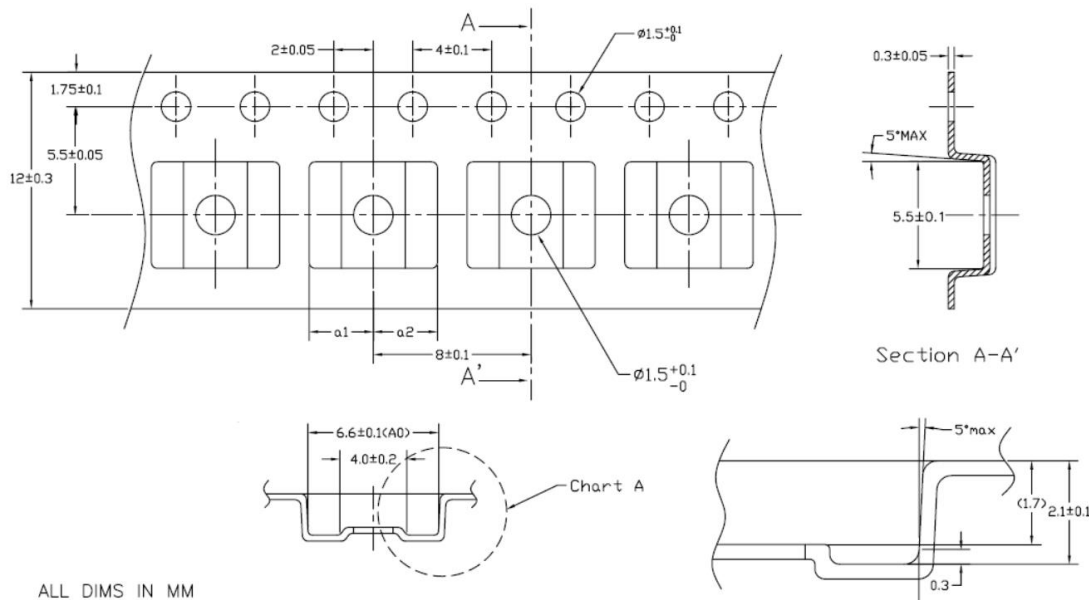


Figure18. Common-mode transient immunity (CMTI) measurement

common-mode pulse generator (G_1) will be capable of providing fast rising and falling pulses of specified magnitude and duration of the common-mode pulse (V_{CM}) and the maximum common-mode slew rates (dV_{CM}/dt) can be applied to $\pi 1xxxxx$ isolator coupler under measurement. The common-mode pulse is applied between one side ground GND_1 and the other side ground GND_2 of $\pi 1xxxxx$ isolator and shall be capable of providing positive transients as well as negative transients.

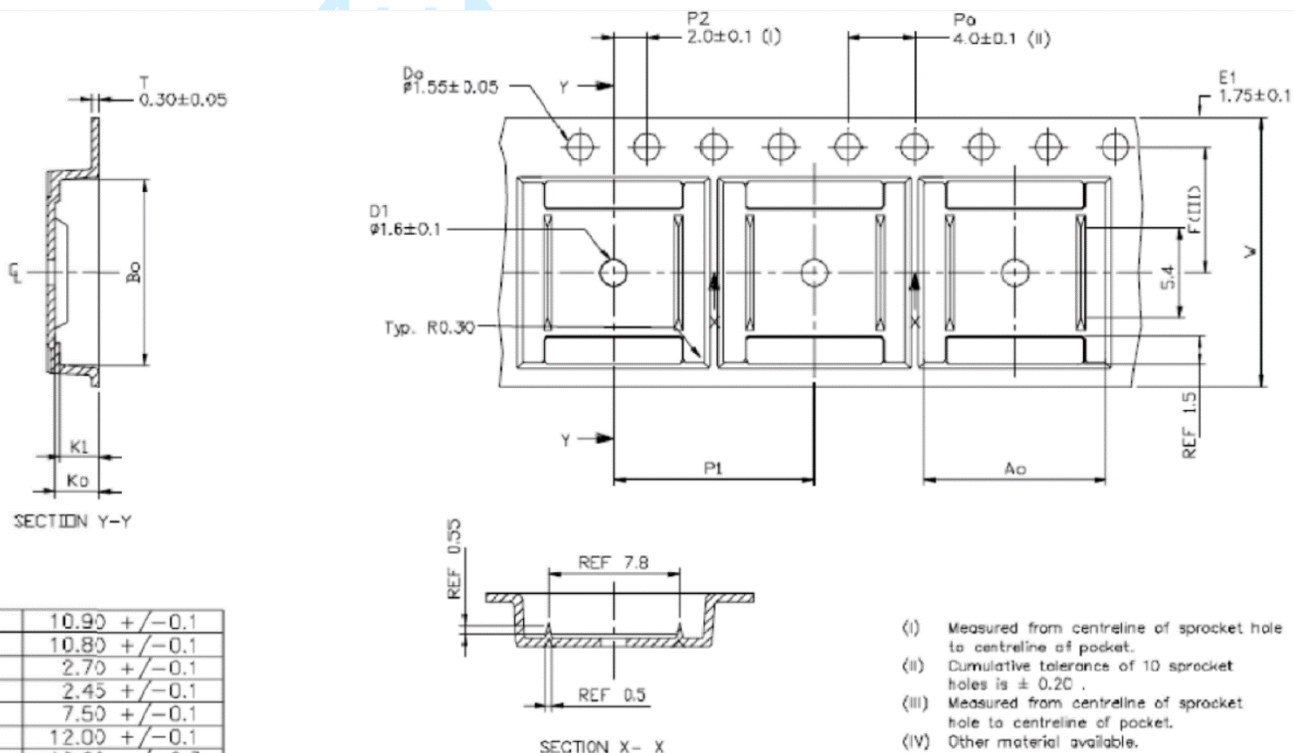
REEL INFORMATION

8-Lead SOIC_N



ALL DIMS IN MM

16-Lead SOIC_W



SECTION Y-Y

SECTION X-X

A ₀	10.90 +/−0.1
B ₀	10.80 +/−0.1
K ₀	2.70 +/−0.1
K ₁	2.45 +/−0.1
F	7.50 +/−0.1
P ₁	12.00 +/−0.1
W	16.00 +/−0.3

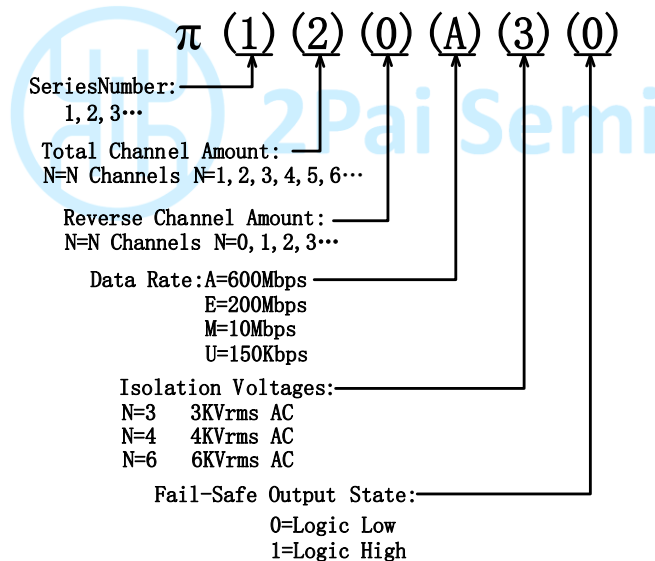
- (i) Measured from centreline of sprocket hole to centreline of pocket.
- (ii) Cumulative tolerance of 10 sprocket holes is ± 0.20 .
- (iii) Measured from centreline of sprocket hole to centreline of pocket.
- (iv) Other material available.

ALL DIMENSIONS IN MILLIMETRES UNLESS OTHERWISE STATED.

ORDERING GUIDE

Model Name		Temperature Range	No. of Inputs, V _{DD1} Side	No. of Inputs, V _{DD2} Side	Withstand Voltage Rating (kV rms)	Fail-Safe Output State	Package Description	Package Option	Quantity
π 120U31	Pai120U31	-40°C to +125°C	2	0	3	High	8-Lead SOIC_N	S-8-N	4000 per reel
π 120U30	Pai120U30	-40°C to +125°C	2	0	3	Low	8-Lead SOIC_N	S-8-N	4000 per reel
π 121U31	Pai121U31	-40°C to +125°C	1	1	3	High	8-Lead SOIC_N	S-8-N	4000 per reel
π 121U30	Pai121U30	-40°C to +125°C	1	1	3	Low	8-Lead SOIC_N	S-8-N	4000 per reel
π 122U31	Pai122U31	-40°C to +125°C	1	1	3	High	8-Lead SOIC_N	S-8-N	4000 per reel
π 122U30	Pai122U30	-40°C to +125°C	1	1	3	Low	8-Lead SOIC_N	S-8-N	4000 per reel
π 120U61	Pai120U61	-40°C to +125°C	2	0	6	High	16-Lead SOIC_W	S-16-W	1000 per reel
π 120U60	Pai120U60	-40°C to +125°C	2	0	6	Low	16-Lead SOIC_W	S-16-W	1000 per reel
π 121U61	Pai121U61	-40°C to +125°C	1	1	6	High	16-Lead SOIC_W	S-16-W	1000 per reel
π 121U60	Pai121U60	-40°C to +125°C	1	1	6	Low	16-Lead SOIC_W	S-16-W	1000 per reel
π 122U61	Pai122U61	-40°C to +125°C	1	1	6	High	16-Lead SOIC_W	S-16-W	1000 per reel
π 122U60	Pai122U60	-40°C to +125°C	1	1	6	Low	16-Lead SOIC_W	S-16-W	1000 per reel

PART NUMBER NAMED RULE



Notes:

Pai12xxxx is equals to π 12xxxx in the customer BOM

REVISION HISTORY

Revision	Updated	Date	Page	Change Record
1	Jason	2018/09/19	All	Initial version
2	Jason	2018/11/28	P11	Changed the recommended bypass capacitor value from between 0.1 μ F and 1 μ F to between 0.1 μ F and 10 μ F.